

Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35511 D

T-29-01

PRO ELECTRON SERIES (Bipolar—see page 5-37 for JFET)



Type No.	Case Style	V _{CE} [*] V _{CB} [*] (V) Min	V _{CE} [*] (V) Min	V _{EB} [*] (V) Min	I _{CS} [*] I _{CS} @ (mA) Max	V _{CB} (V) Max	H _{FE} h _{FE} 1 kHz Min	I _C @ (mA) Max	V _{CE} (V) Max	V _{BE} (V) Min	V _{BE} (V) Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC107	TO-18	50	45	6	15*	50	40 125 40	0.01 500* 2	0.6 0.2	0.55	0.7*	100 10 2	4.5	150	10		10	1	04
BC107A	TO-18	50	45	6	15*	50	125 260*	2 5	0.6 0.2	0.55	0.7*	100 10 2	4.5	150	10		10	1	04
BC107B	TO-18	50	45	6	15*	50	40 240	0.01 500*	0.6 0.2	0.55	0.7*	100 10 2	4.5	150	10		10	1	04
BC108	TO-18	30	20	5	15*	30	40 125	0.01 900*	0.6 0.2	0.55	0.7*	100 10 2	4.5	150	10		10	1	04
BC108A	TO-18	30	20	5	15*	30	40 125	0.01 260*	0.6 0.2	0.55	0.7*	100 100 2	4.5	150	10		10	1	04
BC108B	TO-18	30	20	5	15*	30	40 240	0.01 500*	0.6 0.2	0.55	0.7*	100 10 2	4.5	150	10		10	1	04
BC108C	TO-18	30	20	5	15*	30	40 450	0.01 900*	0.6 0.2	0.55	0.7*	100 10 2	4.5	150	10		10	1	04
BC109	TO-18	30	20	5	15*	30	100 240	0.01 900*	0.6 0.2	0.55	0.7*	100 10 2	4.5	150	10		4	1	04
BC109B	TO-18	30	20	5	15*	30	100 240	0.01 500*	0.6 0.2	0.55	0.7*	100 10 2	4.5	150	10		4	1	04
BC109C	TO-18	30	20	5	15*	30	100 450	0.01 900*	0.6 0.2	0.55	0.7*	100 10 2	4.5	150	10		4	1	04
BC140	TO-39	80*	40	7	100*	60	40	250 100*	1.0	1.8*	1A	25	25	50	50	850		2	14
BC140-6	TO-39	80*	40	7	100*	60	40	100 100*	1.0	1.8*	1A	25	25	50	50	850		2	14
BC140-10	TO-39	80*	40	7	100*	60	63	160 100*	1.0	1.8*	1A	25	25	50	50	850		2	14
BC140-16	TO-39	80*	40	7	100*	60	100	250 100*	1.0	1.8*	1A	25	25	50	50	850		2	14
BC141	TO-39	100*	60	7	100*	60	40	250 100*	1.0	1.8*	1A	25	25	50	50	850		2	14
BC141-6	TO-39	100*	60	7	100*	60	40	100 100*	1.0	1.8*	1A	25	25	50	50	850		2	14
BC141-10	TO-39	100*	60	7	100*	60	63	160 100*	1.0	1.8*	1A	25	25	50	50	850		2	14

6501130 NATL SEMICOND, (DISCRETE)

28C 35512

D

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] (V)	V _{CE} [*] (V)	V _{BO} (V)	I _{CS} [*] (mA)	V _{CB} (V)	H _{FE} h _{FE} @ 1 kHz [*]	I _C & V _{CE} (mA) (V)	V _{CE(SAT)} (V)	V _{BE(SAT)} (V)	I _C (mA)	C _{ob} (pF)	f _T (MHz)	I _C (mA)	t _{off} (ns)	NF (dB)	Test Conditions	Process No.
BC143	TO-5	60	60	5	50	40	20	200 2	1.5	1.5	1.5 500 200	20	60	50				63
BC146-1	TO-92 (94)	20	20	4	50	40	80	200 0.2 1	1.5	1.5	1.5 500 200	20	60	50				04
BC146-2	TO-92 (94)	20	20	4	50	40	140	350 0.2 1	1.5	1.5	1.5 500 200	20	60	50				04
BC146-3	TO-92 (94)	20	20	4	50	40	280	550 0.2 1	1.5	1.5	1.5 500 200	20	60	50				04
BC160	TO-39	40*	5	40	100	40	40	250 100 1	1.0	1.7*	1.7* 1A 30	30	50	50	650		2	67
BC160-6	TO-39	40*	5	40	100	40	40	100 100 1	1.0	1.7*	1.7* 1A 30	30	50	50	650		2	67
BC160-10	TO-39	40*	5	40	100	40	63	160 100 1	1.0	1.7*	1.7* 1A 30	30	50	50	650		2	67
BC160-16	TO-39	40*	5	40	100	40	100	250 100 1	1.0	1.7*	1.7* 1A 30	30	50	50	650		2	67
BC161	TO-39	60*	5	60	100	60	40	250 100 1	1.0	1.7*	1.7* 1A 30	30	50	50	650		2	67
BC161-6	TO-39	60*	5	60	100	60	40	100 100 1	1.0	1.7*	1.7* 1A 30	30	50	50	650		2	67
BC161-10	TO-39	60*	5	60	100	60	63	160 100 1	1.0	1.7*	1.7* 1A 30	30	50	50	650		2	67
BC161-16	TO-39	60*	5	60	100	60	100	250 100 1	1.0	1.7*	1.7* 1A 30	30	50	50	650		2	67
BC167	TO-92 (94)	60*	45	6	15*	50	110 125	500* 2 5	0.2 0.6	0.55 0.7*	10 100	4.5	150	10		10	1	04
BC167A	TO-92 (94)	60*	45	6	15*	50	110 125	260* 2 5	0.2 0.6	0.55 0.7*	10 100	4.5	150	10		10	1	04
BC167B	TO-92 (94)	60*	45	6	15*	50	110 240	500* 2 5	0.2 0.6	0.55 0.7*	10 100	4.5	150	10		10	1	04
BC168	TO-92 (94)		20	5	15*	30	110 125	900* 2 5	0.2 0.6	0.55 0.70*	10 100	4.5	150	10		10	1	04
BC168A	TO-92 (94)		20	5	15*	30	110 125	260* 2 5	0.2 0.6	0.55 0.70*	10 100	4.5	150	10		10	1	04
BC168B	TO-92 (94)		20	5	15*	30	110 240	500* 2 5	0.2 0.6	0.55 0.70*	10 100	4.5	150	10		10	1	04

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz, (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA, (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz, (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA, (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz, (7) I_C = 10V, V_{CE} = 10V, f = 1 kHz, (8) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA, (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

5

T-29-D1

6501130 NATL SEMICON, (DISCRETE)

28C 35513 D

Pro Electron Series

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} * V _{CB} (V) Min	V _{EO} (V) Min	V _{BO} (V) Min	ICES* ICBO (mA) @ VCB (V) Max	HFE h _{FE} @ 1 kHz IC & VCE (mA, V) Min Max	VCE(SAT) (V) Max	VBE(SAT) & VBE(ON)* (V) Min Max	IC (mA) Max	Cob (pF) Max	f _T (MHz) Min Max	IC (mA) @ f _T Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC168C	TO-92 (94)		20	5	15*	110 450	2 900*	5 5	0.2 0.6	10 100	150	10		10	1	04
BC169	TO-92 (94)		20	5	15*	110 240	2 900*	5 5	0.2 0.6	10 100	150	10		4	1	04
BC169B	TO-92 (94)		20	5	15*	110 240	2 500*	5 5	0.2 0.6	10 100	150	10		4	1	04
BC169C	TO-92 (94)		20	5	15*	110 450	2 900*	5 5	0.2 0.6	10 100	150	10		4	1	04
BC177	TO-18	50	45	5	100	110 125	2 500*	5 5	0.18	10 100	150	10		10	1	71
BC177A	TO-18	50	45	5	100	110 125	2 260*	5 5	0.18	10 100	150	10		10	1	71
BC177B	TO-18	50	45	5	100	110 240	2 500*	5 5	0.18	10 100	150	10		10	1	71
BC177VI	TO-18	50	45	5	100	110 75	2 150*	5 5	0.18	10 100	150	10		10	1	71
BC178	TO-18	30	25	5	100	110 125	2 900*	5 5	0.18	10 100	150	10		10	1	71
BC178A	TO-18	30	25	5	100	110 125	2 260*	5 5	0.18	10 100	150	10		10	1	71
BC178B	TO-18	30	25	5	100	110 240	2 500*	5 5	0.18	10 100	150	10		10	1	71
BC179	TO-18	25	20	5	100	110 125	2 900*	5 5	0.18	10 100	150	10		4	1	71
BC179A	TO-18	25	20	5	100	110 125	2 260*	5 5	0.18	10 100	150	10		4	1	71

6501130 NATL SEMICOND, (DISCRETE)

28C 35514

T-29-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CE0} (V) Min	V _{BE} [*] (V) Min	I _{CS} [*] I _{CS0} (mA) Max	H _{FE} h _{FE} 1 kHz [*] Min	I _C & V _{CE} @ (mA) (V) Max	V _{CE} (SAT) (V) Max	V _{BE} (SAT) & V _{BE} (ON) [*] (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC179B	TO-18	25	5	100	110 240	2 500 [*]	0.18	0.78 0.75 [*]	10 2	4.5	150	10		4	1	71
BC182	TO-92 (97)	60	5	15	40 80 125	0.01 100 500 [*]	0.6 0.25	1.2 0.55	100 2	5	150	10		10	1	04
BC182A	TO-92 (97)	60	5	15	40 80 125	0.01 100 260 [*]	0.6 0.25	1.2 0.55	100 2	5	150	10		10	1	04
BC182B	TO-92 (97)	60	5	15	40 80 240	0.01 100 500 [*]	0.6 0.25	1.2 0.55	100 2	5	150	10		10	1	04
BC182L	TO-92 (94)	60	5	15	40 80 125	0.01 100 500 [*]	0.6 0.25	1.2 0.55	100 2	5	150	10		10	1	04
BC182LA	TO-92 (94)	60	5	15	40 80 125	0.01 100 260 [*]	0.6 0.25	1.2 0.55	100 2	5	150	10		10	1	04
BC182LB	TO-92 (94)	60	5	15	40 80 240	0.01 100 500 [*]	0.6 0.25	1.2 0.55	100 2	5	150	10		10	1	04
BC183	TO-92 (97)	45	5	15	40 80 125	0.01 100 900 [*]	0.6 0.25	1.2 0.55	100 2	5	150	10		10	1	04
BC183A	TO-92 (97)	45	5	15	40 80 125	0.01 100 260 [*]	0.6 0.25	1.2 0.55	100 2	5	150	10		10	1	04
BC183B	TO-92 (97)	45	5	15	40 80 240	0.01 100 500 [*]	0.6 0.25	1.2 0.55	100 2	5	150	10		10	1	04
BC183C	TO-92 (97)	45	5	15	40 80 450	0.01 100 900 [*]	0.6 0.25	1.2 0.55	100 2	5	150	10		10	1	04

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

D Pro Electron Series

5

6501130 NATL SEMICOND, (DISCRETE)

28C 35515 D

Pro Electron Series

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CE0} (V) Min	V _{BE} [*] V _{BE0} (V) Min	V _{CE} [*] V _{CE0} (V) Min	V _{BE} [*] V _{BE0} (V) Min	HFE h _{FE} 1 kHz Min	HFE h _{FE} 1 kHz Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Max	V _{CE(SAT)} (V) Min	V _{BE(SAT)} (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C (mA) @ f _T Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC183L	TO-92 (94)	45	30	30	30	40	0.01	5	0.6	0.25	1.2	100	5	150	10		10	1	04
BC183LA	TO-92 (94)	45	30	30	30	40	0.01	5	0.6	0.25	1.2	100	5	150	10		10	1	04
BC183LB	TO-92 (94)	45	30	30	30	40	0.01	5	0.6	0.25	1.2	100	5	150	10		10	1	04
BC183LC	TO-92 (94)	45	30	30	30	40	0.01	5	0.6	0.25	1.2	100	5	150	10		10	1	04
BC184	TO-92 (97)	45	30	30	30	40	0.01	5	0.6	0.25	1.2	100	5	150	10		4	1	04
BC184B	TO-92 (97)	45	30	30	30	40	0.01	5	0.6	0.25	1.2	100	5	150	10		4	1	04
BC184C	TO-92 (97)	45	30	30	30	40	0.01	5	0.6	0.25	1.2	100	5	150	10		4	1	04
BC184L	TO-92 (94)	45	30	30	30	40	0.01	5	0.6	0.25	1.2	100	5	150	10		4	1	04
BC184LB	TO-92 (94)	45	30	30	30	40	0.01	5	0.6	0.25	1.2	100	5	150	10		4	1	04
BC184LC	TO-92 (94)	45	30	30	30	40	0.01	5	0.6	0.25	1.2	100	5	150	10		4	1	04
BC204	TO-92 (92)	50	45	45	45	50	450	2	0.3			10					10	1	71
BC207	TO-92 (92)	50	45	45	45	50	450	2	0.25	0.6		100	6				10	1	04
BC212	TO-92 (97)	60	50	50	50	60	400	2	0.6	0.25	1.1	100	10	200	10		10	1	63

T-29-01



PRO ELECTRON SERIES (Continued)

6501130 NATL SEMICOND, (DISCRETE)

28C 35516

T-29-01

Type No.	Case Style	V _{CE} [*] V Min	V _{CE} (V) Min	V _{EB} (V) Min	I _{CE} [*] I _{CB} @ (mA) Max	HFE h _{FE} 1 kHz [*] Min	HFE h _{FE} 1 kHz [*] Max	V _{CE} (SAT) (V) Max	V _{BE} (ON) [*] (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.	
BC212A	TO-92 (97)	60	50	5	15	30	100	300 [*]	2	5	0.6 0.25	1.1 10	100	10	10	1		63
BC212B	TO-92 (97)	60	50	5	15	30	200	400 [*]	2	5	0.6 0.25	1.1 10	100	10	10	1		63
BC212L	TO-92 (94)	60	50	5	15	30	40 60 60 [*]	0.01 300 2	5 5 2	5	0.6 0.25	1.1 10	100	10	10	1		63
BC212LA	TO-92 (94)	60	50	5	15	30	40 60 100	0.01 2 300 [*]	5 5 2	5	0.6 0.25	1.1 10	100	10	10	1		63
BC212LB	TO-92 (94)	60	50	5	15	30	40 60 200	0.01 2 400 [*]	5 5 2	5	0.6 0.25	1.1 10	100	10	10	1		63
BC213	TO-92 (97)	45	30	5	15	30	40 60 80	0.01 2 600 [*]	5 5 2	5	0.6 0.25	1.1 10	100	10	10	1		63
BC213A	TO-92 (97)	45	30	5	15	30	40 60 100	0.01 2 300 [*]	5 5 2	5	0.6 0.25	1.1 10	100	10	10	1		63
BC213B	TO-92 (97)	45	30	5	15	30	40 60 200	0.01 2 400 [*]	5 5 2	5	0.6 0.25	1.1 10	100	10	10	1		63
BC213C	TO-92 (97)	45	30	5	15	30	40 60 350	0.01 2 600 [*]	5 5 2	5	0.6 0.25	1.1 10	100	10	10	1		63
BC213L	TO-92 (94)	45	30	5	15	30	40 80 80 [*]	0.01 2 400	5 5 2	5	0.6 0.25	1.1 10	100	10	10	1		63
BC213LA	TO-92 (94)	45	30	5	15	30	40 80 100	0.01 2 300 [*]	5 5 2	5	0.6 0.25	1.1 10	100	10	10	1		63

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

5

Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35517 D

T-29-01



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB} (V) Min	V _{CE} [*] (V) Min	V _{EB} (V) Min	I _{CE} [*] I _{CB} @ (mA) Max	HFE h _{FE} 1 kHz [*] Min Max	V _{CE} (SAT) (V) Max	V _{BE} (ON) [*] (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC213LB	TO-92 (94)	45	30	5	15	40 80 200	0.6 0.25	1.1 0.72 [*]	100 10	10	200	10		10	1	63
BC213LC	TO-92 (94)	45	30	5	15	40 80 350	0.6 0.25	1.1 0.72 [*]	100 10	10	200	10		10	1	63
BC214	TO-92 (97)	45	30	5	15	40 80 140	0.6 0.25	1.1 0.72 [*]	100 10	10	200	10		2	1	63
BC214A	TO-92 (97)	45	30	5	15	40 80 100	0.6 0.25	1.1 0.72 [*]	100 10	10	200	10		2	1	63
BC214B	TO-92 (97)	45	30	5	15	40 80 200	0.6 0.25	1.1 0.72 [*]	100 10	10	200	10		2	1	63
BC214C	TO-92 (97)	45	30	5	15	40 80 350	0.6 0.25	1.1 0.72 [*]	100 10	10	200	10		2	1	63
BC214L	TO-92 (94)	45	30	5	15	100 140 120 140 [*]	0.6 0.25	1.1 0.72 [*]	100 10	10	200	10		2	1	63
BC214LB	TO-92 (94)	45	30	5	15	100 140 120 200	0.6 0.25	1.1 0.72 [*]	100 10	10	200	10		2	1	63
BC214LC	TO-92 (94)	45	30	5	15	100 140 120 350	0.6 0.25	1.1 0.72 [*]	100 10	10	200	10		2	1	63
BC237-92	TO-92 (97)	50	45	6	50	100 140 120 125	0.25	0.77 [*] 0.6	10 100	4.5				10	1	04
BC237A-92	TO-92 (97)	50	45	6	50	100 140 120 125	0.25	0.77 [*] 0.6	10 100	4.5				10	1	04

6501130 NATL SEMICOND, (DISCRETE)

28C 35518

T-24-01

D

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CE0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CE} [*] I _{CE0} (mA) Max	V _{CB} (V) Min	H _{FE} h _{FE} 1 kHz [*] Min	I _C & V _{CE} @ (mA) (V) Max	V _{CE} (SAT) (V) Max	V _{BE} (SAT) & V _{BE} (ON) (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC237B-92	TO-92 (97)	50	45	6	50	20	100 140 120 240	0.01 2 100 500*	0.25	0.77* 0.6 0.55	10 100 2	4.5				10	1	04
BC238-92	TO-92 (97)	30	20	5	50	20	100 140 120 125	0.01 2 100 900*	0.25	0.77* 0.6 0.55	10 100 2	4.5				10	1	04
BC238A-92	TO-92 (97)	30	20	5	50	20	100 140 120 125	0.01 2 100 260*	0.25	0.77* 0.6 0.55	10 100 2	4.5				10	1	04
BC238B-92	TO-92 (97)	30	20	5	50	20	100 140 120 240	0.01 2 100 500*	0.25	0.77* 0.6 0.55	10 100 2	4.5				10	1	04
BC238C-92	TO-92 (97)	30	20	5	50	20	100 140 120 450	0.01 2 100 900*	0.25	0.77* 0.6 0.55	10 100 2	4.5				10	1	04
BC239-92	TO-92 (97)	30	20	5	50	20	100 140 120 240	0.01 2 100 900*	0.25	0.77* 0.6 0.55	10 100 2	4.5				4	1	04
BC239B-92	TO-92 (97)	30	20	5	50	20	100 140 120 240	0.01 2 100 500*	0.25	0.77* 0.6 0.55	10 100 2	4.5				4	1	04
BC239C-92	TO-92 (97)	30	20	5	50	20	100 140 120 450	0.01 2 100 900*	0.25	0.77* 0.6 0.55	10 100 2	4.5				4	1	04
BC261A	TO-18		45		50	45	100 140 120 125	0.01 2 100 260*	0.25 0.6	0.9 0.70	10 100 2	4.5				6	3	71

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 μA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 μA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

5

Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35519 D

T-29-01



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} ⁺ V _{CB} (V) Min	V _{CE} (V) Min	V _{EB} (V) Min	I _{CE} ⁺ I _{CB} (mA) Max	HFE h _{FE} @ 1 kHz Min Max	I _C & V _{CE} (mA) (V) Min Max	V _{CE} (SAT) (V) Max	V _{BE} (ON) ⁺ (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC261B	TO-18		45		50	100 140 120 240	0.01 2 100 500*	0.25 0.6	0.9	10 100					6	3	71
BC262A	TO-18		20	5	50	100 140 120	0.01 2 100	0.25	0.9	10					6	3	71
BC262B	TO-18		20	5	50	100 140 120 240	0.01 2 100 500*	0.25 0.6	0.9	10 100					6	3	71
BC263A	TO-18		20	5	50	100 140 120	0.01 2 100	0.25	0.9	10					2.5	3	71
BC263B	TO-18		20	5	50	100 140 120 240	0.01 2 100 500*	0.25 0.6	0.9	10 100					2.5	3	71
BC307-92	TO-92 (97)	50	45	5	100	100 140 120 75	0.01 2 100 500*	0.18	0.78 1.0*	10 100 2					10	1	71
BC307A-92	TO-92 (97)	50	45	5	100	100 140 120 240	0.01 2 100 500*	0.18	0.78 1.0*	10 100 2					10	1	71
BC307B-92	TO-92 (97)	50	45	5	100	100 140 120 240	0.01 2 100 500*	0.18	0.78 1.0*	10 100 2					10	1	71
BC308-92	TO-92 (97)	30	25	5	100	100 140 120 240	0.01 2 100 500*	0.18	0.78 1.0*	10 100 2					10	1	71
BC308A-92	TO-92 (97)	30	25	5	100	100 140 120 240	0.01 2 100 500*	0.18	0.78 1.0*	10 100 2					10	1	71

6501130 NATL SEMICOND, (DISCRETE)

28C 35520

D

Pro Electron Series

5

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CEO} (V) Min	V _{EB} [*] V _{BO} (V) Min	I _{CE} [*] I _{BO} (mA) Max	V _{CE} (V) I _C (mA) Min	HFE h _{FE} 1 kHz Min	HFE h _{FE} 1 kHz Max	V _{CE} (SAT) (V) Max	V _{BE} (SAT) (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	NF (dB) Max	Test Conditions	Process No.
BC308B-92	TO-92 (97)	30	25	100	5	100	0.01 5	0.18	0.78	10				10	1	71
BC308C-92	TO-92 (97)	30	25	100	5	140	400 2 5	0.18	0.78	10				10	1	71
BC309-92	TO-92 (97)	25	20	100	5	120	500* 2 5	0.18	0.78	10				4	1	71
BC309B-92	TO-92 (97)	25	20	100	5	140	400 2 5	0.18	0.78	10				4	1	71
BC309C-92	TO-92 (97)	25	20	100	5	120	500* 2 5	0.18	0.78	10				4	1	71
BC317	TO-92 (92)	50	45	30	6	110	450 2 5	0.2	0.77*	10	4			6	1	04
BC317A	TO-92 (92)	50	45	30	6	125	500* 2 5	0.5	0.57	0.72*	4			6	1	04
BC317B	TO-92 (92)	50	45	30	6	200	450 2 5	0.2	0.77*	10	4			6	1	04
BC318	TO-92 (92)	30	20	30	5	110	800 2 5	0.2	0.77*	10	4			6	1	04
BC318A	TO-92 (92)	30	20	30	5	125	900* 2 5	0.5	0.57	0.72*	4			6	1	04

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B = I_C = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B = I_C = 10 mA, V_{CE} = 3V, I_B = I_C = 1 mA. (5) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 150 mA, V_{CE} = 6V, I_B = I_C = 15 mA. (9) I_C = 10 μA, V_{CE} = 5V, f = WB.

6501130 NATL SEMICOND, (DISCRETE)

28C 35521 D

Pro Electron Series

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE} [*] V _{CB} (V) Min	V _{CE} [*] (V) Min	V _{EB} [*] (V) Min	I _{CS} [*] I _{CB} (mA) Max	HFE h _{FE} 1 kHz Min Max	I _C & V _{CE} (mA) (V) Min Max	V _{CE} (SAT) (V) Max	V _{BE} (SAT) & V _{BE} (ON) (V) Min Max	I _C (mA) Min Max	Cob (pF) Max	f _T (MHz) Min Max	I _C (mA) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC318B	TO-92 (92)	30	20	5	30	200 450 240	2 5 2	0.2 0.5	0.77* 0.72* 0.57	10 100 2	4				6	1	04
BC318C	TO-92 (92)	30	20	5	30	100 450 240	0.01 2 5	0.2 0.5	0.77* 0.72* 0.57	10 100 2	4				6	1	04
BC319	TO-92 (92)	30	20	5	30	40 200 240	0.01 2 5	0.2 0.5	0.77* 0.72* 0.57	10 100 2	4				4	1	04
BC319B	TO-92 (92)	30	20	5	30	200 450 240	2 5 2	0.2 0.5	0.77* 0.72* 0.57	10 100 2	4				4	1	04
BC319C	TO-92 (92)	30	20	5	30	100 420 450	0.01 2 5	0.2 0.5	0.77* 0.72* 0.57	10 100 2	4				4	1	04
BC327	TO-92 (97)	50†	45	5	100†	40 100 63	300 100 1	0.7	12* 1.2* 1.2*	500 300 300	4				4	1	67
BC327-10	TO-92 (97)	50†	45	5	100†	40 63 100	300 100 1	0.7	12* 1.2* 1.2*	500 300 300	4				4	1	67
BC327-16	TO-92 (97)	50†	45	5	100†	40 100 160	300 100 1	0.7	12* 1.2* 1.2*	500 300 300	4				4	1	67
BC327-25	TO-92 (97)	50†	45	5	100†	40 160 100	300 100 1	0.7	12* 1.2* 1.2*	500 300 300	4				4	1	67
BC328	TO-92 (97)	30†	25	5	100†	40 100 63	300 100 1	0.7	12* 1.2* 1.2*	500 300 300	4				4	1	67
BC328-10	TO-92 (97)	30†	25	5	100†	40 63 100	300 100 1	0.7	12* 1.2* 1.2*	500 300 300	4				4	1	67
BC328-16	TO-92 (97)	30†	25	5	100†	40 100 160	300 100 1	0.7	12* 1.2* 1.2*	500 300 300	4				4	1	67
BC328-25	TO-92 (97)	30†	25	5	100†	40 160 100	300 100 1	0.7	12* 1.2* 1.2*	500 300 300	4				4	1	67
BC337	TO-92 (97)	50†	45	5	100†	40 100 63	300 100 1	0.7	1.2* 1.2* 1.2*	500 300 300	4				4	1	14
BC337-10	TO-92 (97)	50†	45	5	100†	40 63 100	300 100 1	0.7	1.2* 1.2* 1.2*	500 300 300	4				4	1	14
BC337-16	TO-92 (97)	50†	45	5	100†	40 100 160	300 100 1	0.7	1.2* 1.2* 1.2*	500 300 300	4				4	1	14
BC337-25	TO-92 (97)	50†	45	5	100†	40 160 100	300 100 1	0.7	1.2* 1.2* 1.2*	500 300 300	4				4	1	14

5-12

6501130 NATL SEMICOND, (DISCRETE)

28C 35522

T-29-01



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} ¹ (V) Min	V _{CE} ² (V) Min	V _{BO} ³ (V) Min	I _{CS} ⁴ (mA) Max	V _{CB} (V) Max	f _{hfe} 1 kHz ⁵ Min Max	I _C & V _{CE} (mA) & (V) Min Max	V _{CE} (SAT) (V) Max	V _{BE} (ON) ⁶ (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC338	TO-92 (97)	30 ¹	25	5	100 ¹	25	40 300 1	300 1	0.7	1.2 ²	500 300	4				4	1	14
BC338-10	TO-92 (97)	30 ¹	25	5	100 ¹	25	40 300 1	300 1	0.7	1.2 ²	500 300	4				4	1	14
BC338-16	TO-92 (97)	30 ¹	25	5	100 ¹	25	40 300 1	300 1	0.7	1.2 ²	500 300	4				4	1	14
BC338-25	TO-92 (97)	30 ¹	25	5	100 ¹	25	40 300 1	300 1	0.7	1.2 ²	500 300	4				4	1	14
BC415	TO-92 (97)	45	35	5	15	30	40 0.01 5	0.01 5	0.25	0.6	10					2	10	71
BC415A	TO-92 (97)	45	35	5	15	30	40 0.01 5	0.01 5	0.25	0.6	10					2	10	71
BC415B	TO-92 (97)	45	35	5	15	30	40 0.01 5	0.01 5	0.25	0.6	10					2	10	71
BC415C	TO-92 (97)	45	35	5	15	30	40 0.01 5	0.01 5	0.25	0.6	10					2	10	71
BC485	TO-92 (97)	45	45	5	100	30	15 1A 5	1A 5	0.5	1.2 500 300	4					4	1	14
BC485A	TO-92 (97)	45	45	5	100	30	40 10 2	10 2	0.5	1.2 500 300	4					4	1	14
BC485B	TO-92 (97)	45	45	5	100	30	15 1A 5	1A 5	0.5	1.2 500 300	4					4	1	14
BC485L	TO-92 (97)	45	45	5	100	30	40 10 2	10 2	0.5	1.2 500 300	4					4	1	14
BC547	TO-92 (97)	50	45	6	10	20	125 500 ⁵ 2	5	0.25 0.6	0.77 ⁶ 10 100 2	4.5					10	1	04
BC547A	TO-92 (97)	50	45	6	10	20	125 260 ⁵ 2	5	0.25 0.6	0.77 ⁶ 10 100 2	4.5					10	1	04

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

5

Pro Electron Series

6501130 NATL SEMICON, (DISCRETE)

28C 35523 D

T-29-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} * V _{CE} (V) Min	V _{BO} (V) Min	I _{CE} * I _{CE} (mA) Max	HFE h _{FE} @ 1 kHz Min Max	V _{CE} (SAT) (V) Max	V _{BE} (SAT) & V _{BE} (ON) (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC547B	TO-92 (97)	50	45	6	10	20	0.25 0.6	0.77* 100	4.5				10	1	04
BC547C	TO-92 (97)	50	45	6	10	20	0.25 0.6	0.77* 100	4.5				10	1	04
BC548	TO-92 (97)	30	20	5	10	20	0.25 0.6	0.77* 100	4.5				10	1	04
BC548A	TO-92 (97)	30	20	5	10	20	0.25 0.6	0.77* 100	4.5				10	1	04
BC548B	TO-92 (97)	30	20	5	10	20	0.25 0.6	0.77* 100	4.5				10	1	04
BC548C	TO-92 (97)	30	20	5	10	20	0.25 0.6	0.77* 100	4.5				10	1	04
BC549	TO-92 (97)	30	20	5	10	20	0.25 0.6	0.77* 100	4.5				4	1	04
BC549B	TO-92 (97)	30	20	5	10	20	0.25 0.6	0.77* 100	4.5				4	1	04
BC549C	TO-92 (97)	30	20	5	10	20	0.25 0.6	0.77* 100	4.5				4	1	04
BC550	TO-92 (97)	50	45	5	10	45	0.25 0.6	0.77* 100					3	1	04
BC550B	TO-92 (97)	50	45	5	10	45	0.25 0.6	0.77* 100					3	1	04
BC550C	TO-92 (97)	50	45	5	10	45	0.25 0.6	0.77* 100					3	1	04
BC557	TO-92 (97)	50	45	5	100	20	0.3 0.65	0.82* 100					10	1	71

T-29-01

6501130 NATL SEMICOND, (DISCRETE)

28C 35524

D



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} ⁺ V _{CB} (V) Min	V _{CE} (V) Min	V _{BO} (V) Min	I _{CS} ⁺ I _{CB} (mA) Max	HFE h _{FE} 1 kHz Min	I _C & V _{CE} @ (mA) (V) Min	V _{CE} (SAT) (V) Max	V _{BE} (SAT) & V _{BE} (ON) (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC557A	TO-92 (97)	50	45	5	100	125	260* 2 5	0.3 0.65	0.82* 0.6 0.75* 2	10 100					10	1	71
BC557B	TO-92 (97)	50	45	5	100	240	500* 2 5	0.3 0.65	0.82* 0.6 0.75* 2	10 100					10	1	71
BC558	TO-92 (97)	30	25	5	100	75	500* 2 5	0.3 0.65	0.82* 0.6 0.75 2	10 100					10	1	71
BC558A	TO-92 (97)	30	25	5	100	125	260* 2 5	0.3 0.65	0.82* 0.6 0.75 2	10 100					10	1	71
BC558B	TO-92 (97)	30	25	5	100	240	500* 2 5	0.3 0.65	0.82* 0.6 0.75 2	10 100					10	1	71
BC558C	TO-92 (97)	30	25	5	100	450	900* 2 5	0.3 0.65	0.82* 0.6 0.75 2	10 100					10	1	71
BC559	TO-92 (97)	25	20	5	100	125	500* 2 5	0.3 0.65	0.82* 0.6 0.75* 2	10 100					4	1	71
BC559A	TO-92 (97)	25	20	5	100	125	260* 2 5	0.3 0.65	0.82* 0.6 0.75* 2	10 100					4	1	71
BC559B	TO-92 (97)	25	20	5	100	240	500* 2 5	0.3 0.65	0.82* 0.6 0.75* 2	10 100					4	1	71
BC559C	TO-92 (97)	25	20	5	100	450	900* 2 5	0.3 0.65	0.82* 0.6 0.75* 2	10 100					4	1	71
BC560	TO-92 (97)	50	45	5	100	125	500* 2 5	0.3 0.65	0.82* 0.6 0.75* 2	10 100					2	1	71

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

5

Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35525

D

T-29-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CEO (V) Min}	V _{CE} (V) Min	V _{BO} (V) Min	I _{CE} [*] I _{CEO} (mA) Max	HFE h _{FE} 1 kHz Min Max	I _C & V _{CE} (mA) (V) Min Max	V _{CE} (SAT) (V) Max	V _{BE} (SAT) (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC560A	TO-92 (97)	50	45	5	100	125 260*	2 5	0.3 0.65	0.82* 0.75* 2	100					2	1	71
BC560B	TO-92 (97)	50	45	5	100	240 500*	2 5	0.3 0.65	0.82* 0.75* 2	100					2	1	71
BC560C	TO-92 (97)	50	45	5	100	450 900*	2 5	0.3 0.65	0.82* 0.75* 2	100					2	1	71
BCX58	TO-92 (97)		32	7	10	120 630 80 1000 40	2 5 10 1 100 1					125	10	800	6	3/4	04
BCX58-7	TO-92 (97)		32	7	10	120 220 80 10 40	2 5 10 1 100 1					125	10	800	6	3/4	04
BCX58-8	TO-92 (97)		32	7	10	20 310 180 400 45	0.01 5 2 5 10 1					125	10	800	6	3/4	04
BCX58-9	TO-92 (97)		32	7	10	40 460 250 630 60	0.01 5 2 5 10 1					125	10	800	6	3/4	04
BCX58-10	TO-92 (97)		32	7	10	100 630 380 1000 60	0.01 5 2 5 10 1					125	10	800	6	3/4	04
BCX59	TO-92 (97)		45	7		120 630 80 1000 40	2 5 10 1 100 1	0.5	1.0	100		125	10	800		5	04
BCX59-7	TO-92 (97)		45	7		120 220 80 10 40	2 5 10 1 100 1	0.5	1.0	100		125	10	800		5	04
BCX59-8	TO-92 (97)		45	7		20 310 180 400 45	0.01 5 2 5 10 1	0.5	1.0	100		125	10	800		5	04
BCX59-9	TO-92 (97)		45	7		40 460 250 630 60	0.01 5 2 5 10 1	0.5	1.0	100		125	10	800		5	04

6501130 NATL SEMICOND, (DISCRETE)

28C 35526

D

Pro Electron Series

5

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CE0} (V) Min	V _{BE} [*] V _{BE0} (V) Min	I _{CE} [*] I _{CE0} (mA) Max	V _{CB} (V) Max	HFE h _{FE} 1 kHz [*] Min Max	I _C & V _{CE} (mA) (V) Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) & V _{BE(ON)} [*] (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BCX59-10	TO-92 (97)	45	7			100 630 2 5 380 630 2 5 240 1000 10 1 60 100 1	0.01 5 2 5 10 1 100 1	0.5	1.0	100		125	10	800		5	04
BCX78	TO-92 (97)	32	5			120 630 2 5 80 1000 10 1 40 100 1	0.01 5 2 5 10 1 100 1	0.6	1.0	100							71
BCX78-7	TO-92 (97)	32	5			120 220 2 5 80 10 10 1 40 100 1	2 5 10 1 100 1	0.6	1.0	100							71
BCX78-8	TO-92 (97)	32	5			30 310 2 5 180 310 2 5 120 400 10 1 45 100 1	0.01 5 2 5 10 1 100 1	0.6	1.0	100							71
BCX78-9	TO-92 (97)	32	5			40 460 2 5 250 460 2 5 160 630 10 1 60 100 1	0.01 5 2 5 10 1 100 1	0.6	1.0	100							71
BCX78-10	TO-92 (97)	32	5			100 630 2 5 380 630 2 5 240 1000 10 1 60 100 1	0.01 5 2 5 10 1 100 1	0.6	1.0	100							71
BCX79	TO-92 (97)	45	5			80 1000 10 1 40 100 10 1 120 630 2 5	10 1 100 1 2 5	0.6	1.0	100							71
BCX79-7	TO-92 (97)	45	5			120 220 2 5	2 5	0.6	1.0	100							71
BCX79-8	TO-92 (97)	45	5			120 400 10 1 45 100 1 30 0.01 5 180 310 2 5	10 1 100 1 0.01 5 2 5	0.6	1.0	100							71
BCX79-9	TO-92 (97)	45	5			160 630 10 1 60 100 1 40 0.01 5 250 460 2 5	10 1 100 1 0.01 5 2 5	0.6	1.0	100							71

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 5V, f = 1 mA, V_{CE} = 5V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

T-29-01

Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35527 D

T-29-01



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB0} (V) Min	V _{CE0} [*] (V) Min	V _{EB0} (V) Min	I _{CS} [*] I _{CB0} @ (nA) Max	V _{CB} (V) Min	HFE h _{FE} @ 1 kHz [*] Min Max	I _C & V _{CE} (mA) & (V) Min Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min Max	I _C (mA) Min Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BCX79-10	TO-92 (97)		45	5			240 1000 10 1 60 100 1 100 0.01 5 380 630 2 5	0.6 1.0 100	0.6	0.6 0.7* 2								71
BCY56	TO-18	45	45	5	100	20	40 450 2 5 100 500* 2 5 40 0.01 5	0.6 0.7* 2	0.6	0.6 0.7* 2						5	1	04
BCY57	TO-18	25	20	5	100	20	200 800 2 5 240 900* 2 5 100 0.01 5	0.6 0.7* 2	0.6	0.6 0.7* 2						5	1	04
BCY58	TO-18		32	7	10 [†]	32	40 1000 10 1 80 1000 10 1 125 700* 2 5	0.35 0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	0.35	0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	6	6	125 10	800	6	4/1	04	
BCY58-7	TO-18		32	7	10 [†]	32	40 1000 10 1 80 1000 10 1 125 250* 2 5	0.35 0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	0.35	0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	6	6	125 10	800	6	4/1	04	
BCY58-8	TO-18		32	7	10 [†]	32	40 1000 10 1 80 1000 10 1 175 350* 2 5	0.35 0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	0.35	0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	6	6	125 10	800	6	4/1	04	
BCY58-9	TO-18		32	7	10 [†]	32	40 1000 10 1 80 1000 10 1 250 500* 2 5	0.35 0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	0.35	0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	6	6	125 10	800	6	4/1	04	
BCY58-10	TO-18		32	7	10 [†]	32	40 1000 10 1 80 1000 10 1 350 700* 2 5	0.35 0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	0.35	0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	6	6	125 10	800	6	4/1	04	
BCY59	TO-18		45	7	10 [†]	45	40 1000 10 1 80 1000 10 1 125 700* 2 5	0.35 0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	0.35	0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	6	6	125 10	800	6	4/1	04	
BCY59-7	TO-18		45	7	10 [†]	45	40 1000 10 1 80 1000 10 1 125 250* 2 5	0.35 0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	0.35	0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	6	6	125 10	800	6	4/1	04	
BCY59-8	TO-18		45	7	10 [†]	45	40 1000 10 1 80 1000 10 1 175 350* 2 5	0.35 0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	0.35	0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	6	6	125 10	800	6	4/1	04	
BCY59-9	TO-18		45	7	10 [†]	45	40 1000 10 1 80 1000 10 1 250 500* 2 5	0.35 0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	0.35	0.6 0.85 10 0.7 0.75 1.2 100 0.55 0.7* 2	6	6	125 10	800	6	4/1	04	

T-29-01

6501130 NATL SEMICON, (DISCRETE)

28C 35528

D

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} * V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CE} * I _{CB0} @ (mA) Max	H _{FE} h _{FE} 1 kHz* Min	I _C @ (mA) Max	V _{CE} & (V) Max	V _{BE(SAT)} & (V) Max	I _C @ (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C @ (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BCY59-10	TO-18		45	7	10†	45	40 80 350	100 1000 700*	1 1 5	0.35 0.75 0.55	0.85 1.2 0.7*	10 100 2	10	800	6	4/1	04
BCY70	TO-18	50	40	5	10	40	40 45 50 15	0.1 1 10 50	1 1 1 1	0.25 0.6 0.9 1.2	10 10 10 50	250	10	420	6	5/6	71
BCY71	TO-18	45	45	5	500	45	40 80 90 100	0.01 0.1 1 600	1 1 1 1	0.5 0.25 0.6 0.9	1.2 10 10 50	200	10		2	6	71
BCY71A	TO-18	45	45	5	500	45	40 80 90 100	0.01 0.1 1 600	1 1 1 1	0.5 0.25 0.6 0.9	1.2 10 10 50	300	10	420	2	6	71
BCY72	TO-18	25	25	5	500	20	40 50	1 10	1 1	0.25 0.5	10 50	200	10	420	6	5/6	71
BD135	TO-126	45	45	5	100	30	25 40	500 250	2 2	0.5	1.0*	50	50	420	6	5/6	37
BD135-6	TO-126	45	45	5	100	30	25 63 25	150 160 500	2 2 2	0.5	500	50	50				37
BD135-10	TO-126	45	45	5	100	30	25	500	2	0.5	500	50	50				37
BD135-16	TO-126	45	45	5	100	30	25	500	2	0.5	500	50	50				37
BD136	TO-126	45	45	5	100	30	40 25	150 500	2 2	0.5	500	50	50				77
BD136-6	TO-126	45	45	5	100	30	25	500	2	0.5	500	50	50				77
BD136-10	TO-126	45	45	5	100	30	63 25	150 500	2 2	0.5	500	50	50				77
BD136-16	TO-126	45	45	5	100	30	100 25	150 500	2 2	0.5	500	50	50				77
BD137	TO-126	60	60	5	100	30	40 25	150 500	2 2	0.5	500	50	50				38

TEST CONDITIONS:

TEST CONDITIONS:
(1) $I_C = 200 \mu A$, $V_{CE} = 5V$, $f = 1 \text{ kHz}$. (2) $I_C = 100 \text{ mA}$, $V_{CC} = 20V$, $I_B^1 = I_B^2 = 5 \text{ mA}$. (3) $I_C = 200 \mu A$, $V_{CE} = 2V$, $f = 1 \text{ kHz}$. (4) $I_C = 100 \text{ mA}$, $V_{CC} = 10V$, $I_B^1 = I_B^2 = 10 \text{ mA}$. (5) $I_C = 10 \text{ mA}$, $V_{CC} = 3V$, $I_B^1 = I_B^2 = 1 \text{ mA}$. (6) $I_C = 100 \mu A$, $V_{CE} = 5V$, $f = 1 \text{ kHz}$. (7) $I_C = 1 \text{ mA}$, $V_{CE} = 10V$, $I_B^1 = I_B^2 = 1 \text{ mA}$. (8) $I_C = 1 \text{ mA}$, $V_{CE} = 5V$, $f = 1 \text{ kHz}$. (9) $I_C = 150 \text{ mA}$, $V_{CC} = 6V$, $I_B^1 = I_B^2 = 15 \text{ mA}$. (10) $I_C = 10 \mu A$, $V_{CE} = 5V$, $f = \text{WB}$.

Pro Electron Series

5

Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35529 D

T-33-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE0} (V) Min	V _{CE0} (V) Max	V _{BE0} (V) Min	V _{BE0} (V) Max	I _{CS0} (mA) Max	H _{FE} h _{FE} 1 kHz Min	I _C (mA) Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD137-6	TO-126	60	60	5	30	100	40	100	2	0.5	500		50	50				38
BD137-10	TO-126	60	60	5	30	100	63	160	2	0.5	500		50	50				38
BD138	TO-126	60	60	5	30	100	40	160	2	0.5	500		50	50				78
BD138-6	TO-126	60	60	5	30	100	40	100	2	0.5	500		50	50				78
BD138-10	TO-126	60	60	5	30	100	63	160	2	0.5	500		50	50				78
BD139	TO-126	80	80	5	30	100	25	500	2	0.5	500		50	50		6	5/6	39
BD139-6	TO-126	80	80	5	30	100	40	160	2	0.5	500		50	50				39
BD139-10	TO-126	80	80	5	30	100	40	100	2	0.5	500		50	50				39
BD140	TO-126	80	80	5	30	100	25	500	2	0.5	500		50	50		6	5/6	79
BD157	TO-126	250	250		275	100 μA	40	160	2									36
BD158	TO-126	300	300		325	100 μA	30	240	2									36
BD159	TO-126	350	350		325	100 μA	30	240	2									36
BD185	TO-126	30	30		40	100 μA	40	500	2	1.0	2A							4F
BD186	TO-126	30	30		40	100 μA	15	2A	2	1.0	2A							5F
BD187	TO-126	45	45		55	100 μA	15	2A	2	1.0	2A							4F
BD188	TO-126	45	45		55	100 μA	40	500	2	1.0	2A							5F
BD189	TO-126	60	60		70	100 μA	15	2A	2	1.0	2A							4F
BD190	TO-126	60	60		70	100 μA	40	500	2	1.0	2A							5F
BD201	TO-220	60	45	5	40	10 μA	30	3A	2	1.0	1.5* 3A		3	300	420	6	5/6	4A
BD202	TO-220	60	45	5	40	10 μA	75	235	500	1	1.0	1.5* 3A	3	300	420	6	5/6	5A

6501130 NATL SEMICOND, (DISCRETE)

28C 35530

D

F-33-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] VCBO (V) Min	V _{BE} [*] VCBO (V) Min	V _{CE} [*] VCBO (V) Max	H _{FE} h _{FE} @ 1 kHz Min Max	I _C & V _{CE} (mA) (V)	V _{CE} (SAT) (V) & V _{BE} (ON) [*] (V) (V) Max Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	e _{IC} (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD203	TO-220	60	5		30 30	2 1	1.0	3A		3	300				4A
BD204	TO-220	60	5	10 μA	30 30	2A 1A	1.0	1.5* 3A							5A
BD220	TO-220	70			30 30	120 500	1.0	1.1* 500							4F
BD221	TO-220	40			30 30	120 1A	1.0	1.3* 1A							4F
BD222	TO-220	60			20 80	1.5A 4	1.0	1.5* 1.5A							4F
BD223	TO-220	70			30 120	300 4	1.0	1.1* 500							5F
BD224	TO-220	40			30 120	1A 4	1.0	1.3* 1A							5F
BD225	TO-220	60			20 80	1.5A 4	1.0	1.5* 1.5A							5F
BD233	TO-126	45		100 μA	25 40	1A 2	0.6	1.3* 1A		3	250	420	6	5/6	4F
BD234	TO-126	45		100 μA	25 40	1A 2	0.6	1.3* 1A		3	250	420	6	5/6	5F
BD235	TO-126	60		100 μA	25 40	1A 2	0.6	1.3* 1A		3	250	420	6	5/6	4F
BD236	TO-126	60		100 μA	25 40	1A 2	0.5	1.3* 1A		3	250	420	6	5/6	5F
BD237	TO-126	80		100 μA	25 40	1A 2	0.6	1.3* 1A		3	250	420	6	5/6	4F
BD238	TO-126	80		100 μA	25 40	1A 2	0.6	1.3* 1A		3	250	420	6	5/6	5F
BD239	TO-220	45		200 μA	15 40	1A 4	0.7	1.3* 1A		3	200	420	6	5/6	4F
BD239A	TO-220	60		200 μA	15 40	1A 4	0.7	1.3* 1A		3	200	420	6	5/6	4F
BD239B	TO-220	80		200 μA	15 40	1A 4	0.7	1.3* 1A		3	200	420	6	5/6	4F
BD239C	TO-220	100		200 μA	15 40	1A 4	0.7	1.3* 1A		3	200	420	6	5/6	4F
BD240	TO-220	45		200 μA	15 40	1A 4	0.7	1.3* 1A		3	200	420	6	5/6	5F
BD240A	TO-220	80		200 μA	15 40	1A 4	0.7	1.3* 1A		3	200	420	6	5/6	5F

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

5

6501130 NATL SEMICOND, (DISCRETE)

28C 35531 D

Pro Electron Series

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE} [*] V _{CE0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CS} [*] I _{CS0} @ (V) Max	HFE h _{FE} 1 kHz [*] Min Max	I _C & V _{CE} @ (mA) (V) Min Max	V _{CE} (SAT) (V) & V _{BE} (ON) (V) Min Max	I _C (mA) Min Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) @ Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD240B	TO-220	80	80		200 μA [*] 80	15 40	1A 4 200 4	0.7 1.3 [*] 1A	1A		3	200	420	6	5/6	5F
BD240C	TO-220	80	100		200 μA [*] 100	15 40	1A 4 200 4	0.7 1.3 [*] 1A	1A		3	200	420	6	5/6	5F
BD241	TO-220	80	45		200 μA [*] 45	10 25	3A 4 1A 4	1.3 1.8 [*] 3A	3A		3	500	420	6	5/6	4F
BD241A	TO-220	80	60		200 μA [*] 60	10 25	3A 4 1A 4	1.3 1.8 [*] 3A	3A		3	500	420	6	5/6	4F
BD241B	TO-220	80	80		200 μA [*] 80	10 25	3A 4 1A 4	1.3 1.8 [*] 3A	3A		3	500	420	6	5/6	4F
BD241C	TO-220	80	100		200 μA [*] 100	10 25	3A 4 1A 4	1.3 1.8 [*] 3A	3A		3	500	420	6	5/6	4F
BD242	TO-220	80	45		200 μA [*] 45	10 25	3A 4 1A 4	1.2 1.8 [*] 3A	3A		3	500	420	6	5/6	5E
BD242A	TO-220	80	60		200 μA [*] 60	10 25	3A 4 1A 4	1.2 1.8 [*] 3A	3A		3	500	420	6	5/6	5E
BD242B	TO-220	80	80		200 μA [*] 80	10 25	3A 4 1A 4	1.2 1.8 [*] 3A	3A	3	3	500	420	6	5/6	5E
BD242C	TO-220	80	100		200 μA [*] 100	10 25	3A 4 1A 4	1.2 1.8 [*] 3A	3A		3	500	420	6	5/6	5E
BD243	TO-220		45		400 μA [*] 45	30 15	300 4 3A 4				3	500				4A
BD243A	TO-220		60		400 μA [*] 60	30 15	300 4 3A 4				3	500				4A
BD243B	TO-220		80		400 μA [*] 80	30 15	300 4 3A 4				3	500				4A
BD243C	TO-220		100		400 μA [*] 100	30 15	300 4 3A 4									4A
BD244	TO-220		45		400 μA [*] 45	30 15	300 4 3A 4									4A
BD244A	TO-220		60		400 μA [*] 60	30 15	300 4 3A 4									5A
BD244B	TO-220		80		400 μA [*] 80	30 15	300 4 3A 4				3	500				5A
BD244C	TO-220		100		400 μA [*] 100	30 15	300 4 3A 4				3	500				5A
BD344	TO-126	60	60	5	500 60	60 40	50 1 200 1	0.4	200	20	50	50				78

7-33-01

6501130 NATL SEMICOND, (DISCRETE)

28C 35532

D

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB} (V) Min	V _{CE} [*] V _{CB} (V) Max	V _{BE} (V) Min	V _{BE} (V) Max	I _{CE} [*] I _{CB} (mA) Min	I _{CE} [*] I _{CB} (mA) Max	V _{CE(SAT)} (V) Min	V _{BE(SAT)} (V) Max	I _C (mA) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD345	TO-126	60	60	5	60	50	1	0.4		200	200	20	50	50				38
BD346	TO-220				60	10 μ A	2A	2.5			250	200	4	4				5A
BD347	TO-220				60	10 μ A	2A	2.5			250	200	4	4				4A
BD348	TO-126	80	80	5	60	500	1	0.5		250	50	17	50	50				79
BD349	TO-126				80	500	1	0.5		250	50	15	50	50				39
BD370A	TO-237 (91)	80	45		45	100	2	0.7		1.2* 1A	200	30	50	50	420	6	5/6	78
BD370A-10	TO-237 (91)	80	45		45	100	2	0.7		1.2* 1A	200	30	50	50	420	6	5/6	78
BD370A-16	TO-237 (91)	80	45		45	100	2	0.7		1.2* 1A	200	30	50	50	420	6	5/6	78
BD370A-25	TO-237 (91)	80	45		45	100	2	0.7		1.2* 1A	200	30	50	50	420	6	5/6	78
BD370B	TO-237 (91)	80	60		60	100	1	0.7		1.2* 1A	200	30	50	50	420	6	5/6	78
BD370B-10	TO-237 (91)	80	60		60	100	2	0.7		1.2* 1A	200	30	50	50	420	6	5/6	78
BD370B-16	TO-237 (91)	80	60		60	100	2	0.7		1.2* 1A	200	30	50	50	420	6	5/6	78
BD370B-25	TO-237 (91)	80	60		60	100	2	0.7		1.2* 1A	200	30	50	50	420	6	5/6	78
BD370C	TO-237 (91)	80	80		80	100	1	0.7		1.2* 1A	200	30	50	50	420	6	5/6	78
BD370-6	TO-237 (91)	80	80		80	100	2	0.7		1.2* 1A	200	30	50	50	420	6	5/6	78
BD370C-10	TO-237 (91)	80	80		80	100	1	0.7		1.2* 1A	200	30	50	50	420	6	5/6	78
BD370C-16	TO-237 (91)	80	80		80	100	2	0.7		1.2* 1A	200	30	50	50	420	6	5/6	78

TEST CONDITIONS:

(1) I_C = 200 μ A, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μ A, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μ A, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μ A, V_{CE} = 5V, f = WB.

Pro Electron Series

5

6501130 NATL SEMICOND, (DISCRETE)

28C 35533 D

T-33-01

Pro Electron Series



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} ⁺ V _{CE0} (V) Min	V _{CE} ⁺ V _{CE0} (V) Max	V _{BE} (V) Min	V _{BE} (V) Max	I _{CE} (mA) Max	I _{CE} (mA) Min	V _{CE} (V) Min	V _{CE} (V) Max	I _{CE} (mA) Min	I _{CE} (mA) Max	V _{BE(SAT)} & V _{BE(ON)} (V) Min	V _{BE(SAT)} & V _{BE(ON)} (V) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD370D	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	79
BD370D-6	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	79
BD370D-10	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	79
BD371A	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371A-10	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371A-16	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371A-25	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371B	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371B-10	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371B-16	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371B-25	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371C	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371C-6	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371C-10	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371C-16	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371D	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	39
BD371D-6	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	39
BD371D-10	TO-237 (91)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	39
BD372A	TO-237 (90)	80	100		80	100	25	40	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	78

6501130 NATL SEMICOND, (DISCRETE)

28C 35534

Pro Electron Series

5



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} * V _{CE0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CE0} * I _{CE0} (mA) Max	H _{FE} h _{FE} @ 1 kHz Min Max	I _C & V _{CE} @ (mA) (V) Min Max	V _{CE} (SAT) (V) Max	V _{BE} (ON)* (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD372A-10	TO-237 (90)	80	45		100	25 63	500 2 160 100 1	0.7	1.2*	1A	30	50	420	6	5/6	78
BD372A-16	TO-237 (90)	80	45		100	25 100	500 2 250 100 1	0.7	1.2*	1A	30	50	420	6	5/6	78
BD372A-25	TO-237 (90)	80	45		100	25 160	500 2 400 100 1	0.7	1.2*	1A	30	50	420	6	5/6	78
BD372B	TO-237 (90)	80	60		100	25 40	500 2 400 100 1	0.7	1.2*	1A	30	50	420	6	5/6	78
BD372B-10	TO-237 (90)	80	60		100	25 63	500 2 160 100 1	0.7	1.2*	1A	30	50	420	6	5/6	78
BD372B-16	TO-237 (90)	80	60		100	25 100	500 2 250 100 1	0.7	1.2*	1A	30	50	420	6	5/6	78
BD372B-25	TO-237 (90)	80	60		100	25 160	500 2 400 100 1	0.7	1.2*	1A	30	50	420	6	5/6	78
BD372C	TO-237 (90)	80	80		100	25 40	500 2 400 100 1	0.7	1.2*	1A	30	50	420	6	5/6	78
BD372C-6	TO-237 (90)	80	80		100	25 40	500 2 100 100 1	0.7	1.2*	1A	30	50	420	6	5/6	78
BD372C-10	TO-237 (90)	80	80		100	25 63	500 2 160 100 1	0.7	1.2*	1A	30	50	420	6	5/6	78
BD372C-16	TO-237 (90)	80	100		100	25 100	500 2 250 100 1	0.7	1.2*	1A	30	50	420	6	5/6	78
BD372D	TO-237 (90)	80	100		100	25 100	500 2 400 100 1	0.7	1.2*	1A	30	50	420	6	5/6	79
BD372D-6	TO-237 (90)	80	100		100	25 40	500 2 100 100 1	0.7	1.2*	1A	30	50	420	6	5/6	79
BD372D-10	TO-237 (90)	80	100		100	25 63	500 2 160 100 1	0.7	1.2*	1A	30	50	420	6	5/6	79
BD373A	TO-237 (90)	80	45		100	25 40	500 2 400 100 1	0.7	1.2*	1A	30	50	420	6	5/6	38
BD373A-10	TO-237 (90)	80	45		100	25 63	500 2 160 100 1	0.7	1.2*	1A	30	50	420	6	5/6	38
BD373A-16	TO-237 (90)	80	45		100	25 100	500 2 250 100 1	0.7	1.2*	1A	30	50	420	6	5/6	38

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 5V, f = 1 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

6501130 NATL SEMICOND, (DISCRETE)

28C 35535 D

Pro Electron Series

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE} ⁺ V _{CB} (V) Min	V _{CE} ⁺ V _{CB} (V) Min	V _{BE} (V) Min	I _{CE} ⁺ I _{CB} (mA) Max	H _{FE} h _{FE} @ 1 kHz Min Max	I _C & V _{CE} (mA) (V)	V _{CE} (SAT) (V) Max	V _{BE} (SAT) & V _{BE} (ON) ⁺ (V) Min Max	I _C (mA) e	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) e	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD373A-25	TO-237 (90)	80	45		100	25	500 2	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373B	TO-237 (90)	80	80		100	25	500 2	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373B-10	TO-237 (90)	80	60		100	25	500 2	0.7	1.2*	1A	30	50	200	420	6	5/8	38
BD373B-16	TO-237 (90)	80	60		100	25	500 2	0.7	1.2*	1A	30	50	200	420	6	5/8	38
BD373B-25	TO-237 (90)	80	60		100	25	500 2	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373C	TO-237 (90)	80	80		100	25	500 2	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373C-6	TO-237 (90)	80	80		100	25	500 2	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373C-10	TO-237 (90)	80	80		100	25	500 2	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373C-16	TO-237 (90)	80	80		100	25	500 2	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373D	TO-237 (90)	80	100		100	25	500 2	0.7	1.2*	1A	30	50	200	420	6	5/6	39
BD373D-6	TO-237 (90)	80	100		100	25	500 2	0.7	1.2*	1A	30	50	200	420	6	5/6	39
BD373D-10	TO-237 (90)	80	100		100	25	500 2	0.7	1.2*	1A	30	50	200	420	6	5/6	39
BD375	TO-126	50	45		2 μA	20	1A 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD375-6	TO-126	50	45		2 μA	20	1A 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD375-10	TO-126	50	45		2 μA	20	1A 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD375-16	TO-126	50	45		2 μA	20	1A 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD375-25	TO-126	50	45		2 μA	20	1A 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD376	TO-126	50	45		2 μA	20	1A 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD376-6	TO-126	50	45		2 μA	20	1A 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78

T-33-01

6501130 NATL SEMICOND, (DISCRETE)

28C 35536

D



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB0} (V) Min	V _{CE0} (V) Min	V _{ES0} (V) Min	I _{CS} [*] I _{CB0} (mA) Max	HFE h _{FE} 1 kHz [*] Min Max	I _C & V _{CE} (mA) & (V) Min Max	V _{CE} (SAT) (V) Max	V _{BE} (SAT) & V _{BE} (ON) (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD376-10	TO-126	50	45		2 μA	20 63	1A 2 160 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD376-16	TO-126	50	45		2 μA	20 100	1A 2 200 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD376-25	TO-126	50	45		2 μA	20 150	1A 2 375 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD377	TO-126	75	60		2 μA	20 40	1A 2 375 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD377-6	TO-126	75	60		2 μA	20 40	1A 2 100 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD377-10	TO-126	75	60		2 μA	20 63	1A 2 160 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD377-16	TO-126	75	60		2 μA	20 100	1A 2 250 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD377-25	TO-126	75	60		2 μA	20 150	1A 2 375 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD378	TO-126	75	60		2 μA	20 40	1A 2 375 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD378-6	TO-126	75	60		2 μA	20 40	1A 2 100 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD378-10	TO-126	75	60		2 μA	20 63	1A 2 160 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD378-16	TO-126	75	60		2 μA	20 100	1A 2 250 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD378-25	TO-126	75	60		2 μA	20 150	1A 2 375 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD379	TO-126	100	80		2 μA	20 40	1A 2 375 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	39
BD379-6	TO-126	100	80		2 μA	20 40	1A 2 100 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	39

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (9) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

5

6501130 NATL SEMICOND, (DISCRETE)

28C 35537 D

Pro Electron Series

Type No.	Case Style	V _{CE} [*] V _{CB} [*] (V) Min	V _{CE} [*] V _{CB} [*] (V) Max	V _{BO} (V) Min	I _{CB} [*] (mA) Max	h _{FE} h _{FE} @ 1 kHz Min Max	I _C & V _{CE} (mA) (V) Min Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD379-10	TO-126	80	100	80	2 μA	20 63	1A 2 150 2	1.0	1.5*	30	50	200	420	6	5/6	39
BD379-16	TO-126	80	100	80	2 μA	20 100	1A 2 150 2	1.0	1.5*	30	50	200	420	6	5/6	39
BD379-25	TO-126	80	100	80	2 μA	20 150	1A 2 150 2	1.0	1.5*	30	50	200	420	6	5/6	39
BD380	TO-126	80	100	80	2 μA	20 40	1A 2 150 2	1.0	1.5*	30	50	200	420	6	5/6	79
BD380-6	TO-126	80	100	80	2 μA	20 40	1A 2 150 2	1.0	1.5*	30	50	200	420	6	5/6	79
BD380-10	TO-126	80	100	80	2 μA	20 63	1A 2 150 2	1.0	1.5*	30	50	200	420	6	5/6	79
BD380-16	TO-126	80	100	80	2 μA	20 100	1A 2 150 2	1.0	1.5*	30	50	200	420	6	5/6	79
BD380-25	TO-126	80	100	80	2 μA	20 150	1A 2 150 2	1.0	1.5*	30	50	200	420	6	5/6	79
BD433	TO-126	22†	22†	5	100 μA	50 85	2A 1 500 1	0.5	1.1*		3	250	420	6	5/6	4E
BD434	TO-126	22†	22†	5	100 μA	50 85	2A 1 500 1	0.5	1.1*	30	3	250	420	6	5/6	5E
BD435	TO-126	32†	32†	5	100 μA	50 85	2A 1 500 1	0.5	1.1*	30	3	250	420	6	5/6	4E
BD436	TO-126	32†	32†	5	100 μA	50 85	2A 1 500 1	0.5	1.1*	30	3	250	420	6	5/6	5E
BD437	TO-126	45†	45†	5	100 μA	40 40	2A 1 500 1	0.6	1.2*	30	3	250	420	6	5/6	4E
BD438	TO-126	45†	45†	5	100 μA	40 40	2A 1 500 1	0.6	1.2*	30	3	250	420	6	5/6	5E
BD439	TO-126	60†	60†	5	100 μA	25 40	2A 1 500 1	0.8	1.5*	30	3	250	420	6	5/6	4E

5-28

6501130 NATL SEMICOND, (DISCRETE)

28C 35538

D

Pro Electron Series

5



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} ⁺ V _{CE0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CE} ⁺ I _{CE0} @ (mA) Max	V _{CB} (V) Min	h _{FE} h _{FE} 1 kHz* Min	I _C & V _{CE} @ (mA) (V) Min Max	V _{CE} (SAT) (V) Max	V _{BE} (ON)* (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD440	TO-126	60†	60	5	100 μA	80	25 40 20	2A 1 236 500 1 10 5	0.8	1.5*	2A	80	3	250	420	6	5/6	5E
BD441	TO-126	80†	80	5	100 μA	80	15 40 15	2A 1 236 500 1 10 5	0.8	1.5*	2A	30	3	250	420	6	5/6	4E
BD442	TO-126	80†	80	5	100 μA	80	15 40 15	2A 1 236 500 1 10 5	0.8	1.5*	2A	30	3	250	420	6	5/6	5E
BD533	TO-220	80†	45	5	100 μA	45	25 40 20	2A 2 500 2 10 5	0.8	1.5*	2A	30	3	250	420	6	5/6	4E
BD534	TO-220	80†	45	5	100 μA	45	25 40 20	2A 2 500 2 10 5	0.8	1.5*	2A	30	3	250	420	6	5/6	5E
BD535	TO-220	80†	60	5	100 μA	60	25 40 20	2A 2 500 2 10 5	0.8	1.5*	2A	30	3	250	420	6	5/6	4E
BD536	TO-220	80†	60	5	100 μA	60	25 40 20	2A 2 500 2 10 5	0.8	1.5*	2A	30	3	250	420	6	5/6	5E
BD537	TO-220	80†	80	5	100 μA	80	15 40 15	2A 2 500 2 10 5	0.8	1.5*	2A	30	3	250	420	6	5/6	4E
BD538	TO-220	80†	80	5	100 μA	80	15 40 15	2A 2 500 2 10 5	0.8	1.5*	2A	30	3	250	420	6	5/6	5E
BD633	TO-220	45	45	5	200 μA†	45	25 40	1A 2 25 2	0.6	1.3*	1A	30	3	250	420	6	5/6	4F
BD634	TO-220	45	45	5	200 μA†	45	25 40	1A 2 25 2	0.6	1.3*	1A	30	3	250	420	6	5/6	5F
BD635	TO-220	60	60	5	200 μA†	60	25 40	1A 2 25 2	0.6	1.3*	1A	30	3	250	420	6	5/6	4F

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

T-33-01

6501130 NATL SEMICON, (DISCRETE)

28C 35539 D

7-33-01

Pro Electron Series

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} * V _{CE0} (V) Min	V _{BE0} (V) Min	I _{CE} * I _{CE0} @ (nA) Max	V _{CB} (V) Min	HFE h _{FE} 1 kHz Min	I _C & V _{CE} (mA) Max	V _{CE} (SAT) (V) Max	V _{BE} (SAT) (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD636	TO-220	60	5	200 μA†	60	25	1A 2	0.6	1.3*	1A	30	3	250	420	6	5/6	5F
BD637	TO-220	80	5	200 μA†	100	40	25 2	0.6	1.3*	1A	30	3	250	420	6	5/6	4F
BD638	TO-220	100	5	200 μA†	100	25	1A 2	0.6	1.3	1A	30	3	250	420	6	5/6	5F
BD675	TO-126	45	45	200 μA	45	750	1.5A 3	2.5	2.5*	1.5A	1	1	1.5A				4J
BD675A	TO-126	45	45	200 μA	45	750	2A 3	2.8	2.5*	2A	1	1	1.5A				4J
BD676	TO-126	45	45	200 μA	45	750	1.5A 3V	2.5	2.5*	1.5A	1	1	1.5A				5J
BD676A	TO-126	45	45	200 μA	45	750	2A 3V	2.8	2.5*	2A	1	1	1.5A				5J
BD677	TO-126	60	60	200 μA	60	750	1.5A 3V	2.5	2.5*	1.5A	1	1	1.5A				4J
BD677A	TO-126	60	60	200 μA	60	750	2A 3V	2.8	2.5*	2A	1	1	1.5A				4J
BD678	TO-126	60	60	200 μA	60	750	1.5A 3V	2.5	2.5*	1.5A	1	1	1.5A				5J
BD678A	TO-126	60	60	200 μA	60	750	2A 3V	2.8	2.5*	2A	1	1	1.5A				5J
BD679	TO-126	80	80	200 μA	80	750	1.5A 3V	2.5	2.5*	1.5A	1	1	1.5A				4J
BD679A	TO-126	80	80	200 μA	80	750	2A 3V	2.8	2.5*	2A	1	1	1.5A				4J
BD680	TO-126	80	80	200 μA	80	750	1.5A 3V	2.5	2.5*	1.5A	1	1	1.5A				5J
BD680A	TO-126	80	80	200 μA	80	750	2A 3V	2.8	2.5*	2A	1	1	1.5A				5J
BD681	TO-126	100	100	200 μA	100	750	1.5A 3V	2.5	2.5*	1.5A	1	1	1.5A				4J
BD682	TO-126	100	100	200 μA	100	750	2A 3V	2.8	2.5*	2A	1	1	1.5A				5J
BD733	TO-220	25	5	200 μA†	25	50	2A 1	0.6	1.1*	2A	1	1	1.5A				4F
BD734	TO-220	25	5	200 μA†	25	50	2A 1	0.6	1.1*	2A	1	1	1.5A				5E
BD735	TO-220	35	5	200 μA†	35	40	2A 1	0.6	1.1*	2A	1	1	1.5A				4F
BD736	TO-220	35	5	200 μA†	35	40	2A 1	0.6	1.1*	2A	1	1	1.5A				5E
BD737	TO-220	45	5	200 μA†	45	40	2A 1	0.8	1.1*	2A	1	1	1.5A				4F
BD738	TO-220	45	5	200 μA†	45	40	2A 1	0.8	1.1*	2A	1	1	1.5A				5E
BD795	TO-220	45				40	2A 1	1.0	1.6*	3A	3	3	250				4E
BD796	TO-220	45				25	3A 2	1.0	1.6*	2A	3	3	250				5E
BD797	TO-220	60				40	1A 2	1.0	1.6*	3A	3	3	250				4E

6501130 NATL SEMICOND, (DISCRETE)

28C 35540

D



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} ¹ (V) Min	V _{CE} ² (V) Min	V _{BO} (V) Min	I _{CS} ³ (mA) Max	H _{FE} h _{FE} 1 kHz ⁴ Min Max	I _C & V _{CE} (mA) (V) Min Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD798	TO-220	60			100 μA	40 25	1A 3A	1.0	1.5*	3A		3				5E
BD799	TO-220	80			100 μA	30 15	1A 3A	1.0	1.6*	3A		3				4E
BD800	TO-220	80			100 μA	30 15	1A 3A	1.0	1.5*	3A		3				5E
BD801	TO-220	100			100 μA	30 15	1A 3A	1.0	1.5*	3A		3				4E
BD802	TO-220	100			100 μA	30 15	1A 3A	1.0	1.5*	3A		3				5E
BD895	TO-220	45			200 μA	750	3A		2.5*	3A		1				4K
BD895A	TO-220	45			200 μA	750	4A		2.5*	4A		1				4K
BD896	TO-220	45			200 μA	750	3A		2.5*	3A		1				5K
BD896A	TO-220	45			200 μA	750	4A		2.5*	4A		1				5K
BD897	TO-220	60			200 μA	750	3A		2.5*	3A		1				4K
BD897A	TO-220	60			200 μA	750	4A		2.5*	4A		1				4K
BD898	TO-220	60			200 μA	750	3A		2.5*	3A		1				5K
BD898A	TO-220	60			200 μA	750	4A		2.5*	4A		1				5K
BD899	TO-220	80			200 μA	750	3A		2.5*	3A		1				4K
BD899A	TO-220	80			200 μA	750	4A		2.5*	4A		1				4K
BD900	TO-220	80			200 μA	750	3A		2.5*	3A		1				5K
BD900A	TO-220	80			200 μA	750	4A		2.5*	4A		1				5K
BD901	TO-220	100			200 μA	750	3A		2.5*	3A		1				4K
BD902	TO-220	100			200 μA	750	4A		2.5*	4A		1				4K
BDX33	TO-220	45			1 mA	750	4A		2.5*	4A		20				4K
BDX33A	TO-220	60			1 mA	750	4A		2.5*	4A		20				4K
BDX33B	TO-220	80			1 mA	750	3A		2.5*	3A		20				4K
BDX33C	TO-220	100			1 mA	750	3A		2.5*	3A		20				4K
BDX33D	TO-220	120			1 mA	750	3A		2.5*	3A		20				4K
BDX34	TO-220	45			1 mA	750	4A		2.5*	4A		20				5K
BDX34A	TO-220	60			1 mA	750	4A		2.5*	4A		20				5K
BDX34B	TO-220	80			1 mA	750	3A		2.5*	3A		20				5K

TEST CONDITIONS:
 (1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 μA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA, (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 μA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

T-33-01

Pro Electron Series

5

6501130 NATL SEMICOND, (DISCRETE)

28C 35541 D

Pro Electron Series

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CE0} (V) Min	V _{CE0} (V) Min	V _{BE0} (V) Min	I _{CB0} [*] I _{CB0} (mA) Max	V _{CB} (V) Max	h _{FE} h _{FE} 1 kHz Min Max	I _C & V _{CE} (mA) (V) Max	V _{CE} (SAT) (V) Max	V _{BE} (SAT) (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.	
BDX34C	TO-220		100		1 mA	100	750	3A 3		2.5*	3A		20	1A				5K	
BDX34D	TO-220		120		1 mA	120	750	3A 3		2.5*	3A		20	1A				5K	
BF167	TO-72 (28)	40	30	4	100†	30	26	4 10		0.84*	4							45	
BF180	TO-72 (25)	30	20	3	100	20	13	2 10										41	
BF181	TO-72 (25)	30	20	3	100	20	13	2 10										41	
BF194	TO-92 (98)	Same as BF254, see page 5-33 for explanation																	46
BF195	TO-92 (98)	Same as BF255, see page 5-33 for explanation																	46
BF196	TO-92 (98)	Same as BF198, see below for explanation																	45
BF197	TO-92 (98)	Same as BF199, see below for explanation																	47
BF198	TO-92 (98)	40	30	4	100	40	26	4 10		0.85*	4							45	
BF199	TO-92 (98)	40	25	4	100	40	36	7 10					1100 typ	7				47	
BF200	TO-72 (25)	30	20	3	100	40	15	3 10										41	
BF233-2	TO-92 (96)	30	30	4	100	10	40	1 10		0.65	0.74*	1	1.0	150	1			49	
BF233-3	TO-92 (96)	30	30	4	100	10	60	1 10		0.65	0.74*	1	1.0	150	1			49	
BF233-4	TO-92 (96)	30	30	4	100	10	90	1 10		0.65	0.74*	1	1.0	150	1			49	
BF233-5	TO-92 (96)	30	30	4	100	10	140	1 10		0.65	0.74*	1	1.0	150	1			49	
BF237	TO-92 (98)	45	30	4	100	20			0.25	10								47	
BF238	TO-92 (98)	45	30	4	100	20			0.25	10								47	
BF240	TO-92 (98)	40	40	4	100	20	67	222 1 10		0.65	0.74*	1	0.34	1		3.5	7	47	
BF241	TO-92 (98)	40	40	4	100	20	36	125 1 10		0.65	0.74*	1	0.34	1		3.5	7	47	

7-31-01

7-31-01

6501130 NATL SEMICON D, (DISCRETE)

28C 35542

D



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} * V _{CB} (V) Min	V _{CE} * V _{CB} (V) Min	V _{BE} (V) Min	I _{CB} * I _{CB} (mA) Max	H _{FE} h _{FE} 1 kHz* Min Max	I _C & I _C (mA) Min Max	V _{CE} (SAT) (V) & V _{BE} (ON)* (V) Max Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BF254	TO-92 (98)	30	20	5	100	20	1 10	0.65 0.74*	1	0.34			3.5	7	46
BF255	TO-92 (98)	30	20	5	100	20	1 10	0.65 0.74*	1	0.34			3.5	7	46
BF257	TO-39	100	100	5	50	100	30 10	1.0 0.65 0.74*	30	0.34			3.5	7	48
BF258	TO-39	250	250	5	50	200	30 10	1.0 0.65 0.74*	30	0.34			3.5	7	48
BF259	TO-39	300	300	5	50	250	30 10	1.0 0.65 0.74*	30	0.34			3.5	7	48
BF457	TO-126	100	100	5	50	100	30 10	1.0 0.65 0.74*	30	0.34			3.5	7	48
BF458	TO-126	250	200	5	50	200	30 10	1.0 0.65 0.74*	30	0.34			3.5	7	48
BF459	TO-126	300	300	5	50	250	30 10	1.0 0.65 0.74*	30	0.34			3.5	7	48
BFX13	TO-18	20	15	5	50	15	100 2	0.2 0.78 1	1	6	150		10	8	66
BFX29	TO-5	20	15	5	50	50	50 10	0.4 1.3 150	150	12	100	150		9	63
BFX30	TO-5	65	65	5	50	50	50 10	0.4 1.3 150	150	12	100	150		9	63
BFX37	TO-18	60	60	6	20*	50	10 5	0.4 1.0 50	50	6	40	0.5	3	1	62
BFX65	TO-18	45	45	6	10*	40	10 5	0.25 0.9 10	10	6.5			3	1	62

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (8) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

5

6501130 NATL SEMICOND, (DISCRETE)

28C 35543 D

T-31-01

Pro Electron Series

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE} [*] (V) Min	V _{CE} [*] (V) Max	V _{BO} (V) Min	I _{CB} @ V _{CB} (mA) Max	HFE h _{FE} 1 kHz [*] Min Max	I _C & V _{CE} (mA) (V) Min Max	V _{CE} (SAT) (V) Max	V _{BE} (ON) (V) Min Max	I _C (mA) Min Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BFX84	TO-39	45		6	500	15 20 30	1A 500 10	0.15 0.35 1.0	1.2 1.3 1.5	10 150 500	12	50	50	360		9	14
BFX85	TO-39	45		6	50	15 30 70	1A 500 150	0.15 0.35 1.0	1.2 1.3 1.5	10 150 500	12	50	50	360		9	14
BFX86	TO-39	45		6	50	15 30 70	1A 500 150	0.15 0.35 1.0	1.2 1.3 1.5	10 150 500	12	50	50	360		9	14
BFX87	TO-5	45		6	50	25 40 40	500 150 10	0.4 0.35 1.0	1.3 1.3 1.5	150 30 1A	12	100	50	150		9	63
BFX88	TO-5	45		6	50	25 40 40	500 150 10	0.4 0.35 1.0	1.3 1.3 1.5	150 30 1A	12	100	50	150		9	63
BFY39	TO-18	45	25	5	50	35	10	1.0	1.0	10		150	10				23
BFY39-1	TO-18	45	25	5	50	35	10	1.0	1.0	10		150	10				23
BFY39-2	TO-18	45	25	5	50	100	200	1.0	1.0	10		150	10				23
BFY39-3	TO-18	45	25	5	50	180	400	1.0	1.0	10		150	10				23
BFY50	TO-18	80	35	6	500	20 30 20	10 150 500	0.1 0.1 0.1	1.2 1.2 1.2	10 10 10	12	60	50	360		9	14
BFY51	TO-39	60	30	6	500	30 40 25	10 150 500	0.1 0.1 0.1	1.2 1.2 1.2	10 10 10	12	60	50	360		9	14
BFY52	TO-39	40	20	6	500	15 30 30	1A 500 500	0.1 0.1 0.1	1.2 1.2 1.2	10 10 10	12	60	50	360		9	14
BFY56	TO-39	80	45	5	50	15 20 30	1 500 150	0.3 1.2 1.2	1.5 2.5 2.5	150 1A 1A	25	40	50				14

6501130 NATL SEMICOND, (DISCRETE)

28C 35544

D



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CE0} (V) Min	V _{CE0} (V) Min	V _{BE0} (V) Min	I _{CE} [*] I _{CE0} @ (mA) Max	H _{FE} h _{FE} 1 kHz [*] Min Max	I _C & V _{CE} (mA) (V) Min Max	V _{CE} (SAT) (V) Max	V _{BE} (ON) [*] (V) Min Max	I _C (mA) Min Max	C _{ob} (pF) Max	f _T (MHz) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BFY72	TO-39	50	28	5	40 [*]	15 20 30	0.1 1 10	0.25	1.2	150	8	50	50			19
BFY76	TO-18	45	45	6	20	30 80 140	0.01 0.5 5	0.35	1.6	500	6					
BSX21	TO-18		80		500	20	4		0.9	4		60	4			07
BSX45-6	TO-39	80 [*]	40	7	10 [*]	40	100	1	1.0	500	20	60	50			14
BSX45-10	TO-39	80 [*]	40	7	10 [*]	63	160	1	1.0	500	20	60	50			14
BSX45-16	TO-39	80 [*]	40	7	10 [*]	100	250	1	1.0	500	20	60	50			14
BSX46-6	TO-39	100 [*]	60	7	10 [*]	40	100	1	1.0	500	25	60	50			12
BSX46-10	TO-39	100 [*]	60	7	10 [*]	63	160	1	1.0	500	25	60	50			12
BSX46-16	TO-39	100 [*]	60	7	10 [*]	100	250	1	1.0	500	25	60	50			12
BSX48	TO-18	50	25	5	120	17	100	1	1.5	500	6	250	30			19
BSX88	TO-18	40	15	5	25	15	0.5	1	0.5	0.72	10	300	10			21
BSY38	TO-18	20	12	5	100	30 15	10 45	0.35 1	0.25 0.6	10 100	5	200	10	45	16	21
BSY39	TO-18	20	12	5	100	40 20	10 70	0.35 1	0.25 0.6	10 100	5	200	10	45	16	21
BSY51	TO-18	60	35	5	100	30	150	10	1.0	1.3	150	130	50			19
BSY52	TO-18	60	25	5	100	30	300	150	1.0	1.3	150	130	50			19
BSY53	TO-18	75	30	7	10	20 35	0.1 10	0.6 10	1.3	150	9	150	50			19

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 μA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA, (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA, (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 10 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA, (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

T-31-01

Pro Electron Series

5

6501130 NATL SEMICON, (DISCRETE)

28C 35545 D

Pro Electron Series

T-31-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} * V _{CE0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CE} * I _{CE0} (mA) Max	V _{CB} (V)	HFE h _{FE} @ 1 kHz Min	I _C & V _{CE} @ (mA) (V) Max	V _{CE} (SAT) (V) Max	V _{BE} (SAT) & V _{BE} (ON)* (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BSY54	TO-18	75	30	7	10	60	35 75 100 40	0.1 10 300 500	0.6	1.3	150	9	150	50				19
BSY55A	TO-18	20	15	5	50	16	30 50	1 200	0.35 0.35	0.67 0.87	10	6	200	10				21

TEST CONDITIONS:

TEST CONDITIONS:

(1) $I_C = 200 \mu A$, $V_{CE} = 5V$, $f = 1 \text{ kHz}$. (2) $I_C = 100 \text{ mA}$, $V_{CC} = 20V$, $I_B^1 = I_B^2 = 5 \text{ mA}$. (3) $I_C = 200 \mu A$, $V_{CE} = 2V$, $f = 1 \text{ kHz}$. (4) $I_C = 100 \text{ mA}$, $V_{CC} = 10V$, $I_B^1 = I_B^2 = 10 \text{ mA}$. (5) $I_C = 10 \text{ mA}$, $V_{CC} = 3V$, $I_B^1 = I_B^2 = 1 \text{ mA}$. (6) $I_C = 100 \mu A$, $V_{CE} = 5V$, $f = 1 \text{ kHz}$. (7) $I_C = 1 \text{ mA}$, $V_{CE} = 10V$, $f = 1 \text{ kHz}$. (8) $I_C = 100 \text{ kHz}$. (9) $I_C = 150 \text{ mA}$, $V_{CC} = 6V$, $I_B^1 = I_B^2 = 15 \text{ mA}$. (10) $I_C = 10 \mu A$, $V_{CE} = 5V$, $f = \omega B$.

6501130 NATL SEMICOND, (DISCRETE)

28C 35546

T-31-01

Pro Electron Series

5

PRO ELECTRON SERIES (JFET)

Type No.	Case Style	BV _{GSS} :BV _{GDO} (V) @ I _G (μA)	I _{GSS} I _{DGD} (nA) @ V _{GD} (V)	V _P @ V _{DS} (V) Min Max	I _D (nA)	V _{GS} (V) @ V _{GS} (V) Min Max	I _{DSS} (mA) @ V _{DS} (V) Min Max	R _g (V _{FS}) (mmho) @ f (MHz) Min Max	C _{iss} (pF) @ V _{DS} (V) Typ	V _{GS} (V) Typ	C _{iss} (pF) @ V _{DS} (V) Typ	V _{GS} (V) Typ	NF (dB) @ R _G = 1k f (Hz) * Max Typ	Process No.	Pkg. No.
BF244A	TO-92	30 1	5 20	.5 8 15	10	.4 2.2 15 200	2 6.5 15	3 6.5 .001	4	-1	1.1 20	-1	1.5 100	50	74
BF244B	TO-92	30 1	5 20	.5 8 15	10	1.6 3.8 15 200	6 15 15	3 6.5 .001	4	-1	1.1 20	-1	1.5 100	50	74
BF244C	TO-92	30 1	5 20	.5 8 15	10	3.2 7.5 15 200	12 25 15	3 6.5 .001	4	-1	1.1 20	-1	1.5 100	50	74
BF245A	TO-92	30 1	5 20	.5 8 15	10	.4 2.2 15 200	2 6.5 15	3 6.5 .001	4	-1	1.1 20	-1	1.5 100	50	77
BF245B	TO-92	30 1	5 20	.5 8 15	10	1.6 3.8 15 200	6 15 15	3 6.5 .001	4	-1	1.1 20	-1	1.5 100	50	77
BF245C	TO-92	30 1	5 20	.5 8 15	10	3.2 7.5 15 200	12 25 15	3 6.5 .001	4	-1	1.1 20	-1	1.5 100	50	77
BF246A	TO-92	25 1	5 15	.6 14.5 15	10	1.5 4.0 15 200	30 80 15	8 .001	11	15	3.5 15	0	7.5 800	51	74
BF246B	TO-92	25 1	5 15	.6 14.5 15	10	3.0 7.0 15 200	60 140 15	8 .001	11	15	3.5 15	0	7.5 800	51	74
BF246C	TO-92	25 1	5 15	.6 14.5 15	10	5.5 12 15 200	110 250 15	8 .001	11	15	3.5 15	0	7.5 800	51	74
BF247A	TO-92	25 1	5 15	.6 14.5 15	10	1.5 4.0 15 200	30 80 15	8 .001	11	15	3.5 15	0	7.5 800	51	77
BF247B	TO-92	25 1	5 15	.6 14.5 15	10	3.0 7.0 15 200	60 140 15	8 .001	11	15	3.5 15	0	7.5 800	51	77
BF247C	TO-92	25 1	5 15	.6 14.5 15	10	5.5 12 15 200	110 250 15	8 .001	11	15	3.5 15	0	7.5 800	51	77
BF256A	TO-92	30 1	5 20	.5 8 15	10	.5 7.5 15 200	3 7 15	4.5 .001			.7 20	-1	7.5 800	50	77
BF256B	TO-92	30 1	5 20	.5 8 15	10	.5 7.5 15 200	6 13 15	4.5 .001			.7 20	-1	7.5 800	50	77
BF256C	TO-92	30 1	5 20	.5 8 15	10	.5 7.5 15 200	11 18 15	4.5 .001			.7 20	-1	7.5 800	50	77
BC264A	TO-92	30 1	10 20	.5 15 10	10	2 1.2 15 1000	2 4.5 15	2.5 .001	4.0	15	1.2 15	-1	40* 10*	50	77
BC264B	TO-92	30 1	10 20	.5 15 10	10	4 1.4 15 1500	3.5 6.5 15	3.0 .001	4.0	15	1.2 15	-1	40* 10*	50	77
BC264C	TO-92	30 1	10 20	.5 15 10	10	5 1.5 15 2500	5.0 8.0 15	3.5 .001	4.0	15	1.2 15	-1	40* 10*	50	77
BC264D	TO-92	30 1	10 20	.5 15 10	10	6 1.6 15 3500	7.0 12.0 15	4.0 .001	4.0	15	1.2 15	-1	40* 10*	50	77